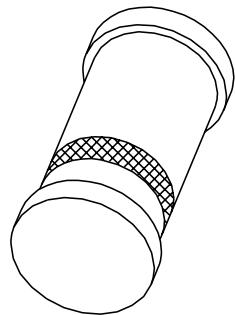


DATA SHEET



PMLL5225B to PMLL5267B Voltage regulator diodes

Product specification
Supersedes data of November 1993

1996 Apr 26

Voltage regulator diodes

PMLL5225B to PMLL5267B

FEATURES

- Total power dissipation: max. 500 mW
- Tolerance series: $\pm 5\%$
- Working voltage range: nom. 3.0 to 75 V
- Non-repetitive peak reverse power dissipation: max. 40 W.

DESCRIPTION

Low-power voltage regulator diodes in small hermetically sealed glass SOD80C SMD packages. The series consists of 43 types with nominal working voltages from 3.0 to 75 V.

APPLICATIONS

- Low-power voltage stabilizers or voltage references.

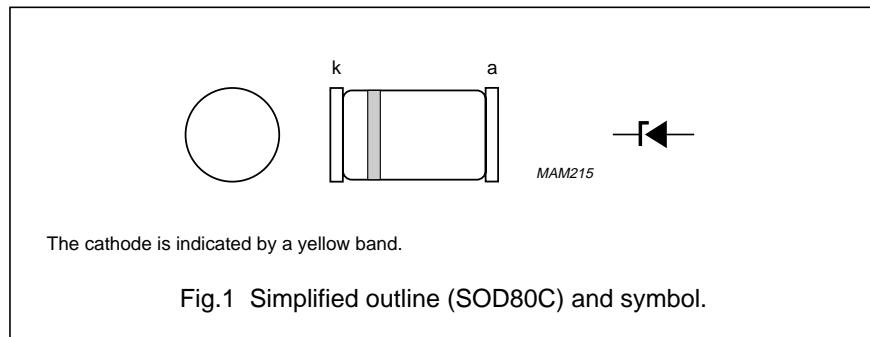


Fig.1 Simplified outline (SOD80C) and symbol.

LIMITING VALUES

In accordance with the Absolute Maximum Rating System (IEC 134).

SYMBOL	PARAMETER	CONDITIONS	MIN.	MAX.	UNIT
I_F	continuous forward current		–	250	mA
I_{ZSM}	non-repetitive peak reverse current	$t_p = 100 \mu s$; square wave; $T_j = 25^\circ C$ prior to surge	see Table "Per type"		
P_{tot}	total power dissipation	$T_{amb} = 25^\circ C$; note 1	–	500	mW
P_{ZSM}	non-repetitive peak reverse power dissipation	$t_p = 100 \mu s$; square wave; $T_j = 25^\circ C$ prior to surge; see Fig.3	–	40	W
		$t_p = 8.3 \text{ ms}$; square wave; $T_j \leq 55^\circ C$ prior to surge	–	10	W
T_{stg}	storage temperature		–65	+200	°C
T_j	junction temperature		–65	+200	°C

Note

1. If flanges are kept at $T_{flange} \leq 75^\circ C$.

ELECTRICAL CHARACTERISTICS

Total series

$T_j = 25^\circ C$; unless otherwise specified.

SYMBOL	PARAMETER	CONDITIONS	MIN.	MAX.	UNIT
V_F	forward voltage	$I_F = 200 \text{ mA}$; see Fig.4	–	1.1	V

Per type

 $T_j = 25^\circ\text{C}$; unless otherwise specified.

TYPE No.	WORKING VOLTAGE V_z (V) ⁽¹⁾ at I_z test	DIFFERENTIAL RESISTANCE r_{dif} (Ω) at I_z test	TEMP. COEFF. S_z (%/K) at I_z ⁽²⁾	TEST CURRENT I_z test (mA)	DIODE CAP. C_d (pF) at $f = 1$ MHz; at $V_R = 0$ V	REVERSE CURRENT at REVERSE VOLTAGE		NON-REPETITIVE PEAK REVERSE CURRENT I_{zSM} (A) at $t_p = 100$ μs ; $T_{\text{amb}} = 25^\circ\text{C}$
						I_R (μA)	V_R (V)	
	NOM.	MAX.	MAX.	MAX.	MAX.	MAX.	MAX.	MAX.
PMLL5225B	3.0	1600	-0.075	20	450	50	1.0	6.0
PMLL5226B	3.3	1600	-0.070	20	450	25	1.0	6.0
PMLL5227B	3.6	1700	-0.065	20	450	15	1.0	6.0
PMLL5228B	3.9	1900	-0.060	20	450	10	1.0	6.0
PMLL5229B	4.3	2000	± 0.055	20	450	5	1.0	6.0
PMLL5230B	4.7	1900	± 0.030	20	450	5	1.5	6.0
PMLL5231B	5.1	1600	± 0.030	20	300	5	2.0	6.0
PMLL5232B	5.6	1600	$+0.038$	20	300	5	3.0	6.0
PMLL5233B	6.0	1600	$+0.038$	20	300	5	3.5	6.0
PMLL5234B	6.2	1000	$+0.045$	20	200	5	4.0	6.0
PMLL5235B	6.8	750	$+0.050$	20	200	3	5.0	6.0
PMLL5236B	7.5	500	$+0.058$	20	150	3	6.0	4.0
PMLL5237B	8.2	500	$+0.062$	20	150	3	6.5	4.0
PMLL5238B	8.7	600	$+0.065$	20	150	3	6.5	3.5
PMLL5239B	9.1	600	$+0.068$	20	150	3	7.0	3.0
PMLL5240B	10	600	$+0.075$	20	90	3	8.0	3.0
PMLL5241B	11	600	$+0.076$	20	85	2	8.4	2.5
PMLL5242B	12	600	$+0.077$	20	85	1	9.1	2.5
PMLL5243B	13	600	$+0.079$	9.5	80	0.5	9.9	2.5
PMLL5244B	14	600	$+0.082$	9.0	80	0.1	10.0	2.0
PMLL5245B	15	600	$+0.082$	8.5	75	0.1	11.0	2.0
PMLL5246B	16	600	$+0.083$	7.8	75	0.1	12.0	1.5
PMLL5247B	17	600	$+0.084$	7.4	75	0.1	13.0	1.5
PMLL5248B	18	600	$+0.085$	7.0	70	0.1	14.0	1.5
PMLL5249B	19	600	$+0.086$	6.6	70	0.1	14.0	1.5
PMLL5250B	20	600	$+0.086$	6.2	60	0.1	15.0	1.5

TYPE No.	WORKING VOLTAGE V_Z (V) ⁽¹⁾ at I_{Ztest}	DIFFERENTIAL RESISTANCE r_{dif} (Ω) at I_{Ztest}	TEMP. COEFF. S_Z (%/K) at I_Z ⁽²⁾	TEST CURRENT I_{Ztest} (mA)	DIODE CAP. C_d (pF) at $f = 1$ MHz; at $V_R = 0$ V	REVERSE CURRENT at REVERSE VOLTAGE		NON-REPETITIVE PEAK REVERSE CURRENT I_{ZSM} (A) at $t_p = 100$ μ s; $T_{amb} = 25$ °C
						I_R (μ A)	V_R (V)	
	NOM.	MAX.	MAX.	MAX.	MAX.	MAX.	MAX.	MAX.
PMLL5251B	22	600	+0.087	5.6	60	0.1	17.0	1.25
PMLL5252B	24	600	+0.088	5.2	55	0.1	18.0	1.25
PMLL5253B	25	600	+0.089	5.0	55	0.1	19.0	1.25
PMLL5254B	27	600	+0.090	4.6	50	0.1	21.0	1.0
PMLL5255B	28	600	+0.091	4.5	50	0.1	21.0	1.0
PMLL5256B	30	600	+0.091	4.2	50	0.1	23.0	1.0
PMLL5257B	33	700	+0.092	3.8	45	0.1	25.0	0.9
PMLL5258B	36	700	+0.093	3.4	45	0.1	27.0	0.8
PMLL5259B	39	800	+0.094	3.2	45	0.1	30.0	0.7
PMLL5260B	43	900	+0.095	3.0	40	0.1	33.0	0.6
PMLL5261B	47	1000	+0.095	2.7	40	0.1	36.0	0.5
PMLL5262B	51	1100	+0.096	2.5	40	0.1	39.0	0.4
PMLL5263B	56	1300	+0.096	2.2	40	0.1	43.0	0.3
PMLL5264B	60	1400	+0.097	2.1	40	0.1	46.0	0.3
PMLL5265B	62	1400	+0.097	2.0	35	0.1	47.0	0.3
PMLL5266B	68	1600	+0.097	1.8	35	0.1	52.0	0.25
PMLL5267B	75	1700	+0.098	1.7	35	0.1	56.0	0.2

Notes

1. V_Z is measured with device at thermal equilibrium while held in clips at 10 mm from body in still air at 25 °C.
2. For types PMLL5225B to PMLL5242B the I_Z current is 7.5 mA; for PMLL5243B and higher $I_Z = I_{Ztest}$. S_Z values valid between 25 °C and 125 °C.

Voltage regulator diodes

PMLL5225B to PMLL5267B

THERMAL CHARACTERISTICS

SYMBOL	PARAMETER	CONDITIONS	VALUE	UNIT
$R_{th\ j\-\!tp}$	thermal resistance from junction to tie-point	lead length 10 mm	300	K/W
$R_{th\ j\-\!a}$	thermal resistance from junction to ambient	lead length max.; see Fig.2 and note 1	380	K/W

Note

1. Device mounted on a printed circuit-board without metallization pad.

Voltage regulator diodes

PMLL5225B to PMLL5267B

GRAPHICAL DATA

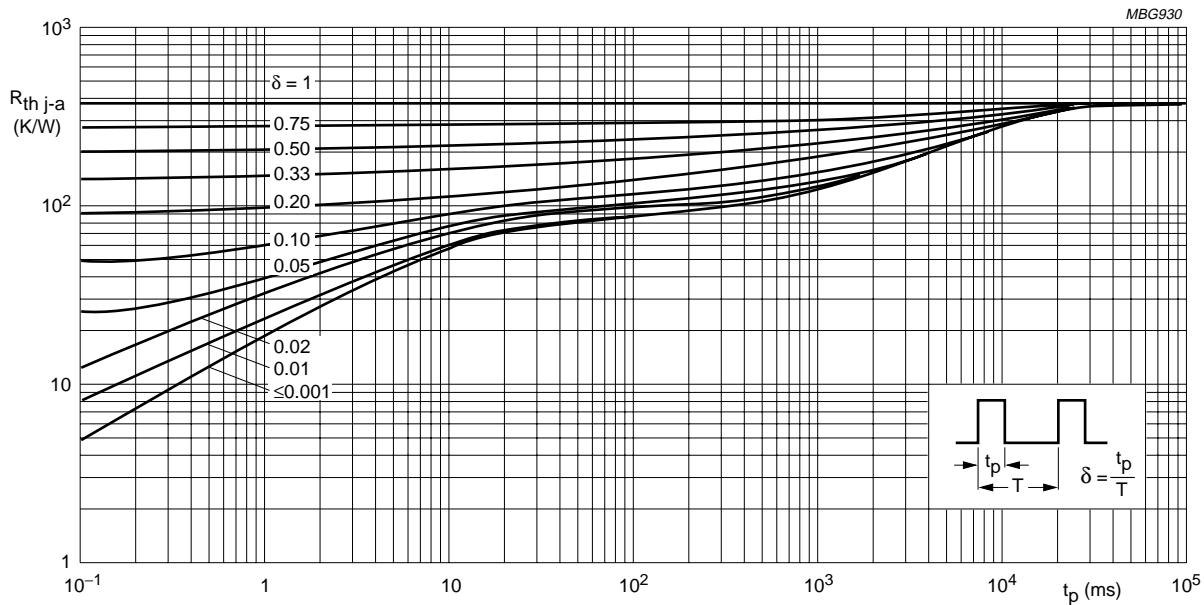
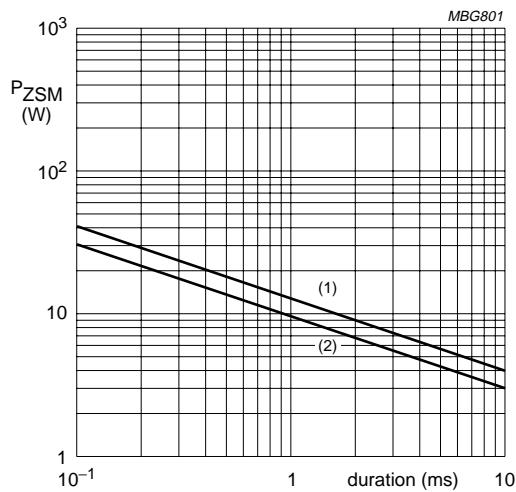


Fig.2 Thermal resistance from junction to ambient as a function of pulse duration.



(1) $T_j = 25 \text{ } ^\circ\text{C}$ (prior to surge).
 (2) $T_j = 150 \text{ } ^\circ\text{C}$ (prior to surge).

Fig.3 Maximum permissible non-repetitive peak reverse power dissipation versus duration.

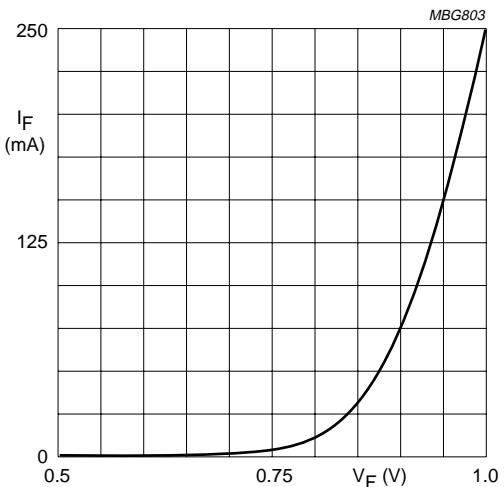
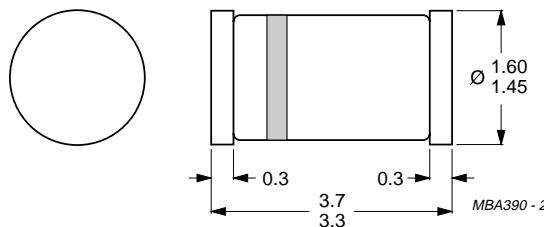
 $T_j = 25 \text{ } ^\circ\text{C}$.

Fig.4 Forward current as a function of forward voltage; typical values.

Voltage regulator diodes

PMLL5225B to PMLL5267B

PACKAGE OUTLINE



Dimensions in mm.

Fig.5 SOD80C.

DEFINITIONS

Data sheet status	
Objective specification	This data sheet contains target or goal specifications for product development.
Preliminary specification	This data sheet contains preliminary data; supplementary data may be published later.
Product specification	This data sheet contains final product specifications.
Limiting values	
Limiting values given are in accordance with the Absolute Maximum Rating System (IEC 134). Stress above one or more of the limiting values may cause permanent damage to the device. These are stress ratings only and operation of the device at these or at any other conditions above those given in the Characteristics sections of the specification is not implied. Exposure to limiting values for extended periods may affect device reliability.	
Application information	
Where application information is given, it is advisory and does not form part of the specification.	

LIFE SUPPORT APPLICATIONS

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